

30V N-Channel Power MOSFET



SOT-26

1. Dra 2. Dra 3. Ga

Pin Definition:

Drain
 Drain
 Drain
 Drain
 Gate
 Source

Note:

MSL 1 (Moisture Sensitivity Level) per J-STD-020

Key Parameter Performance

Parameter		Value	Unit	
$V_{ t DS}$		30	٧	
R _{DS(on)} (max)	V _{GS} = 10V	24	mΩ	
	V _{GS} = 4.5V	34		
Q_{g}		4.1	nC	

Features

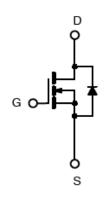
- Halogen-free
- Improved dV/dt capability
- Fast Switching

Ordering Information

Ordering code	Package	Packing		
TSM240N03CX6 RFG	SOT-26	3kpcs / 7" Reel		

Note: Halogen-free according to IEC 61249-2-21 definition

Block Diagram



N-Channel MOSFET

Absolute Maximum Ratings (T_C = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V _{GS}	±20	V
Continuous Drain Current	$T_C = 25^{\circ}C$	l _D	6.5	Α
	$T_C = 100$ °C		4.1	Α
Pulsed Drain Current (Note 1)		I _{DM}	26	Α
Single Pulse Avalanche Energy (Note 2)		E _{AS}	32	mJ
Power Dissipation @ T _C = 25°C		P _D	1.56	W
Operating Junction Temperature		T _J	150	°C
Storage Temperature Range		T _{STG}	-55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Ambient	$R_{\Theta JA}$	80	°C/W



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Electrical Specifications (T_C = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	30			V
	$V_{GS} = 10V, I_D = 6A$	_		17	24	mΩ
Drain-Source On-State Resistance	$V_{GS} = 4.5V, I_D = 4A$	$R_{DS(on)}$		22	34	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	$V_{GS(TH)}$	1.2	1.4	2.5	V
	$V_{DS} = 30V, V_{GS} = 0V$				1	μА
Zero Gate Voltage Drain Current	V _{DS} = 24V, T _J = 125°C	I _{DSS}			10	
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±100	nA
Forward Transconductance (Note 3)	$V_{DS} = 10V, I_{D} = 4A$	g _{fs}		6.5		S
Dynamic				l		
Total Gate Charge (Note 3,4)		Q_g		4.1		nC
Gate-Source Charge (Note 3,4)	$V_{DS} = 15V, I_{D} = 6A,$	Q_gs		1		
Gate-Drain Charge (Note 3,4)	$V_{GS} = 4.5V$	Q_{gd}		2.1		
Input Capacitance		C _{iss}		345		
Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$	C _{oss}		55		pF
Reverse Transfer Capacitance	- f = 1.0MHz	C _{rss}		32		
Switching				l		
Turn-On Delay Time (Note 3,4)		t _{d(on)}		2.8		
Turn-On Rise Time (Note 3,4)	$V_{DD} = 15V, I_{D} = 1A,$	t _r		7.2		
Turn-Off Delay Time (Note 3,4)	$V_{GS} = 10V, R_{GEN} = 6\Omega$	t _{d(off)}		15.8		ns
Turn-Off Fall Time (Note 3,4)		t _f		4.6		
Source-Drain Diode Ratings and Ch	aracteristic			l		
Maximum Continuous Drain-Source		ı			6.5	Α
Diode Forward Current	Integral reverse diode in the MOSFET	I _S			0.0	A
Maximum Pulse Drain-Source Diode		I _{SM}			26	Α
Forward Current						
Diode-Source Forward Voltage	$V_{GS} = 0V$, $I_S = 1A$	$V_{\sf SD}$			1	V

Note:

- 1. Pulse width limited by safe operating area
- 2. L = 1mH, I_{AS} = 8A, V_{DD} = 25V, R_G = 25 Ω , Starting T_J = 25 $^{\circ}$ C
- 3. Pulse test: pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$
- 4. Switching time is essentially independent of operating temperature.

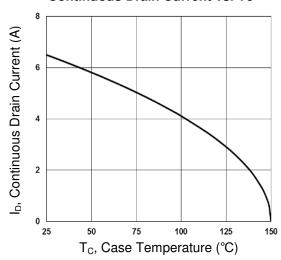


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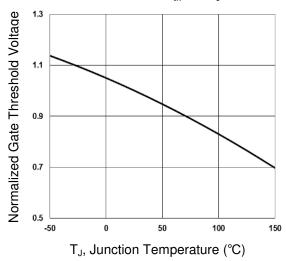


Electrical Characteristics Curve

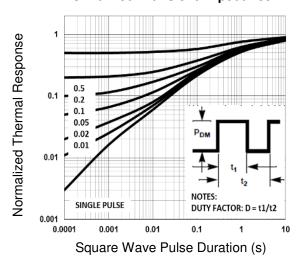
Continuous Drain Current vs. Tc



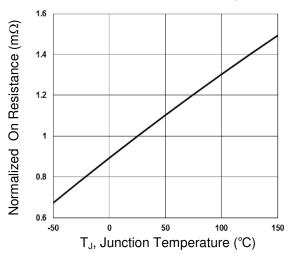
Normalized V_{th} vs. T_J



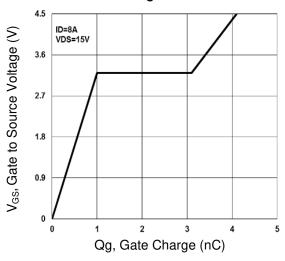
Normalized Transient Impedance



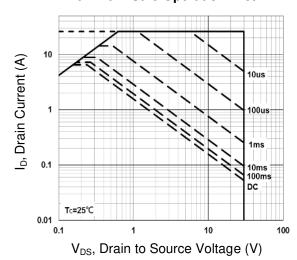
Normalized RDSON vs. T_J



Gate Charge Waveform



Maximum Safe Operation Area

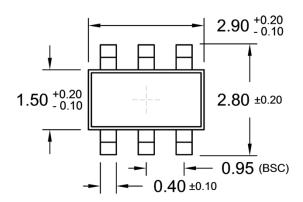


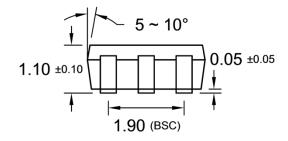


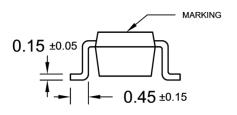
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SOT-26 Mechanical Drawing

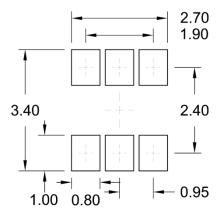






Unit: Millimeters

SUGGESTED PAD LAYOUT (Unit: Millimeters)



Marking Diagram



24 = Device Code

Y = Year Code

M = Month Code for Halogen Free Product (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)

L = Lot Code



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TSM240N03CX6 30V N-Channel Power MOSFET

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